



SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 6 GHz

Typical Applications

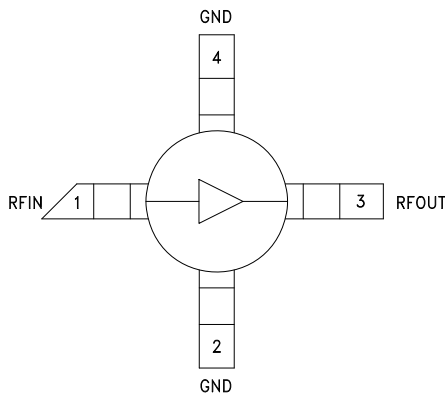
The HMC476MP86 / HMC476MP86E is an ideal RF/IF gain block & LO or PA driver for:

- Cellular / PCS / 3G
- Fixed Wireless & WLAN
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment

Features

- P1dB Output Power: +12 dBm
- Gain: 20 dB
- Output IP3: +25 dBm
- Cascadable 50 Ohm I/Os
- Single Supply: +5V to +12V
- Included in the HMC-DK001 Designer's Kit

Functional Diagram



General Description

The HMC476MP86 & HMC476MP86E are SiGe Heterojunction Bipolar Transistor (HBT) Gain Block MMIC SMT amplifiers covering DC to 6 GHz. This Micro-P packaged amplifier can be used as a cascadable 50 Ohm RF/IF gain stage as well as a LO or PA driver with up to +13 dBm output power. The HMC476MP86 & HMC476MP86E offers 20 dB of gain with a +25 dBm output IP3 at 850 MHz while requiring only 35 mA from a single positive supply. The Darlington feedback pair used results in reduced sensitivity to normal process variations and excellent gain stability over temperature while requiring a minimal number of external bias components.

Electrical Specifications, $V_s = 5V$, $R_{bias} = 56 \text{ Ohm}$, $T_A = +25^\circ \text{ C}$

Parameter		Min.	Typ.	Max.	Units
Gain	DC - 1.0 GHz	18.5	20.0		dB
	1.0 - 2.0 GHz	15.5	17.0		dB
	2.0 - 3.0 GHz	13.5	15.0		dB
	3.0 - 4.0 GHz	11.5	13.0		dB
	4.0 - 6.0 GHz	9.0	10.5		dB
Gain Variation Over Temperature	DC - 6 GHz		0.008	0.012	dB/ °C
Input Return Loss	DC - 1.0 GHz		20		dB
	1.0 - 6.0 GHz		15		dB
Output Return Loss	DC - 4.5 GHz		20		dB
	4.5 - 6.0 GHz		13		dB
Reverse Isolation	DC - 6 GHz		18		dB
Output Power for 1 dB Compression (P1dB)	0.5 - 5.0 GHz	9.0	12.0		dBm
	5.0 - 6.0 GHz	8.0	11.0		dBm
Output Third Order Intercept (IP3) (Pout= 0 dBm per tone, 1 MHz spacing)	DC - 5 GHz		25		dBm
	5.0 - 6.0 GHz		23		dBm
Noise Figure	DC - 3.0 GHz		2.5		dB
	3.0 - 6.0 GHz		3.5		dB
Supply Current (Icq)			35		mA

Note: Data taken with broadband bias tee on device output.

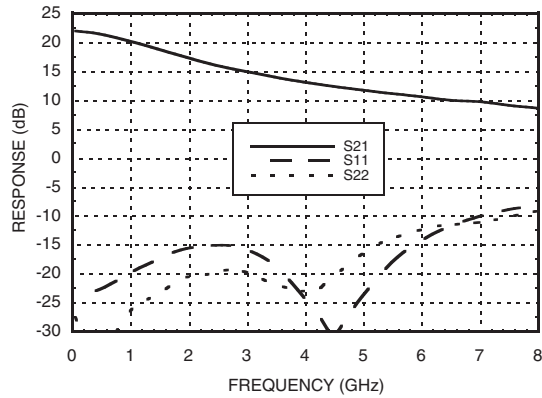
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D

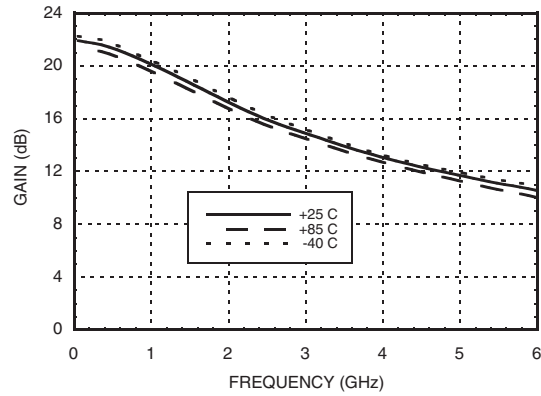


**SiGe HBT GAIN BLOCK
MMIC AMPLIFIER, DC - 6 GHz**

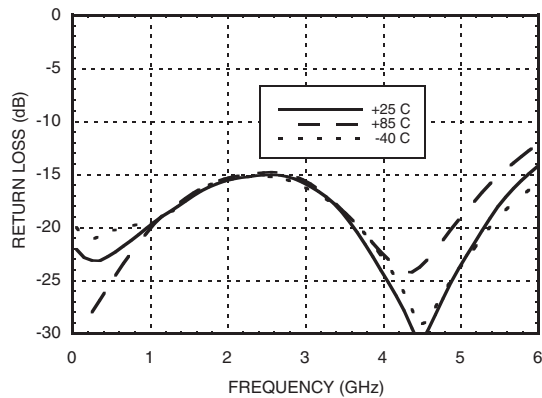
Broadband Gain & Return Loss



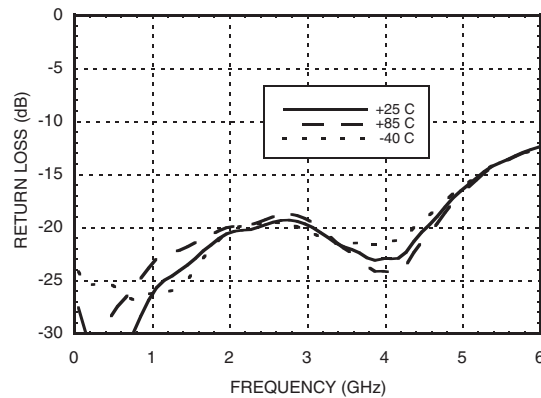
Gain vs. Temperature



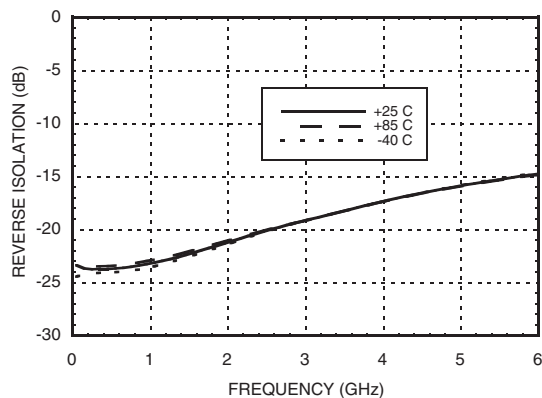
Input Return Loss vs. Temperature



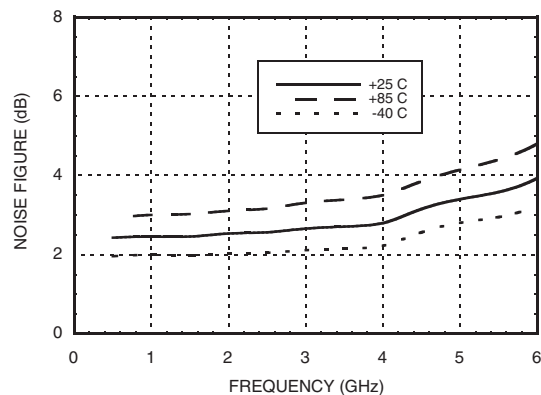
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



Noise Figure vs. Temperature



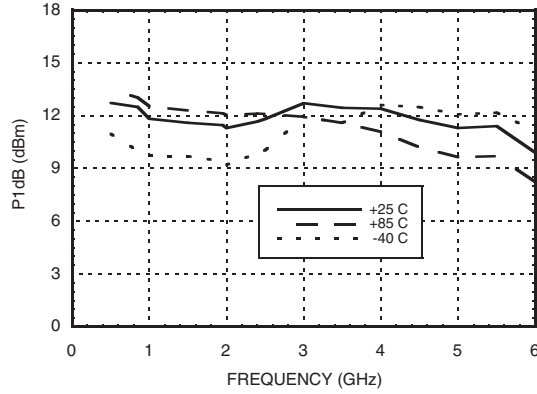


**SiGe HBT GAIN BLOCK
MMIC AMPLIFIER, DC - 6 GHz**

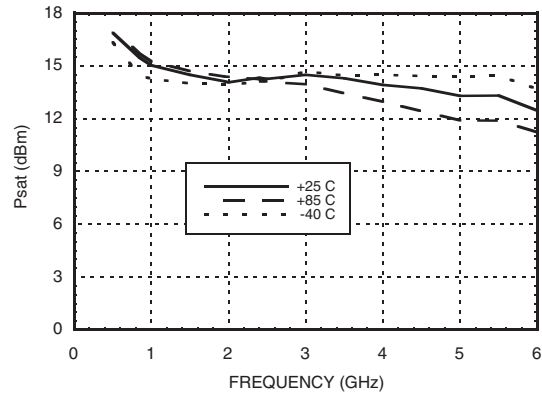
8

AMPLIFIERS - DRIVER & GAIN BLOCK - SMT

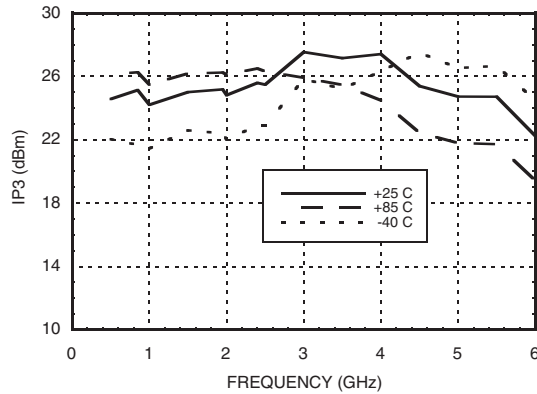
P1dB vs. Temperature



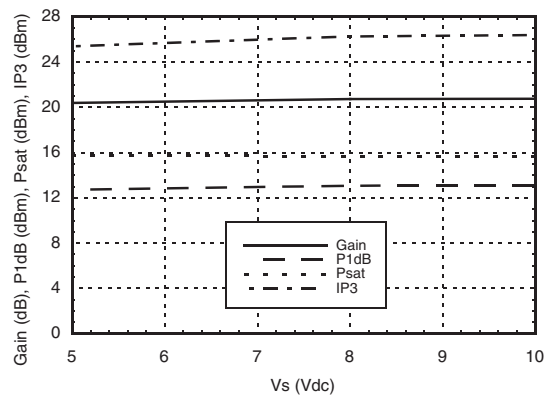
Psat vs. Temperature



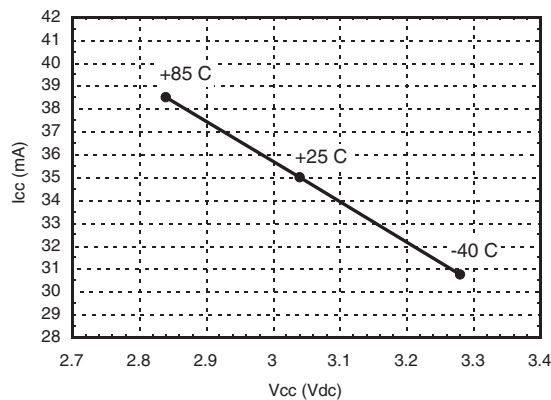
Output IP3 vs. Temperature



Gain, Power & OIP3 vs. Supply Voltage for Constant Id= 35 mA @ 850 MHz



Vcc vs. Icc Over Temperature for Fixed Vs= 5V, RBIAS= 56 Ohms



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D



SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 6 GHz

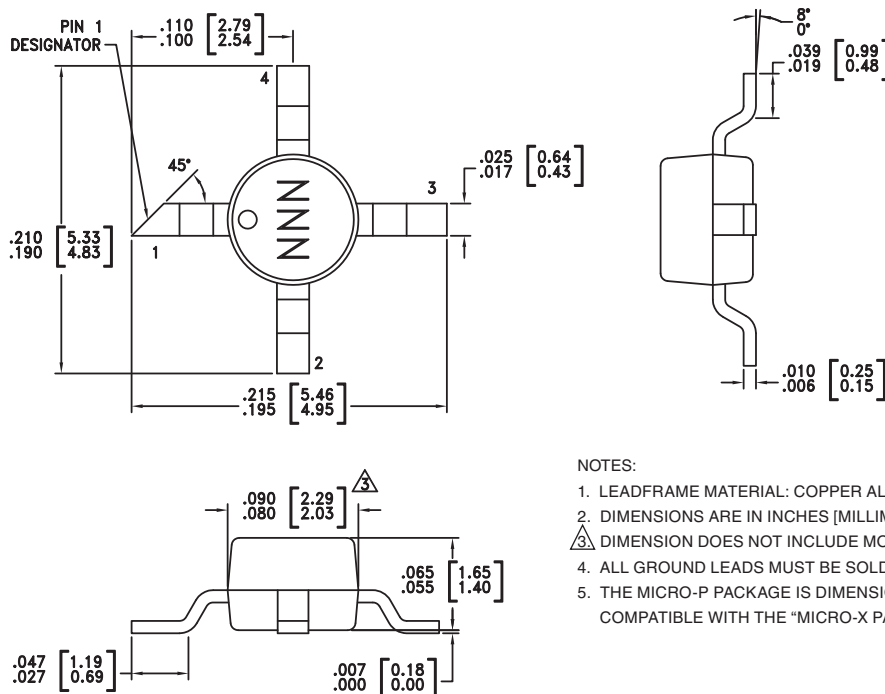
Absolute Maximum Ratings

Collector Bias Voltage (Vcc)	+6.0 Vdc
Collector Bias Current (Icc)	45 mA
RF Input Power (RFIN)(Vcc = +3.0 Vdc)	+5 dBm
Junction Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 7.75 mW/°C above 85 °C)	0.504 W
Thermal Resistance (junction to lead)	129 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



- NOTES:
- LEADFRAME MATERIAL: COPPER ALLOY
 - DIMENSIONS ARE IN INCHES [MILLIMETERS]
 - DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
 - ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
 - THE MICRO-P PACKAGE IS DIMENSIONALLY COMPATIBLE WITH THE "MICRO-X PACKAGE"

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking
HMC476MP86	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	476
HMC476MP86E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>476</u>

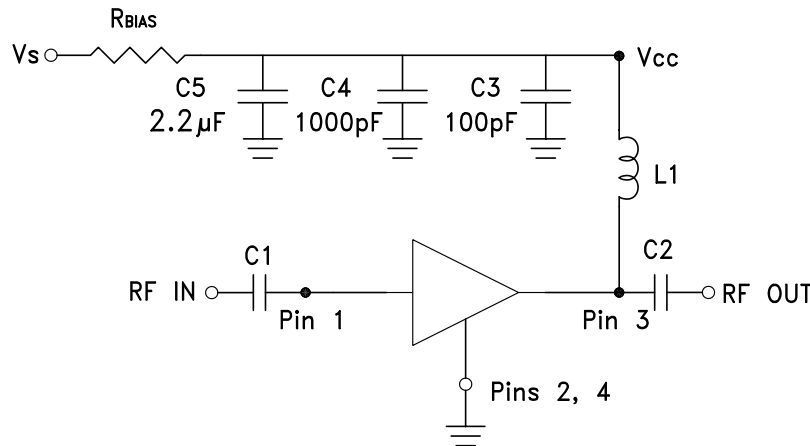
[1] Max peak reflow temperature of 235 °C
[2] Max peak reflow temperature of 260 °C



Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN	This pin is DC coupled. An off chip DC blocking capacitor is required.	
3	RFOUT	RF output and DC Bias (Vcc) for the output stage.	
2, 4	GND	These pins must be connected to RF/DC ground.	

Application Circuit



Recommended Bias Resistor Values for $I_{cc} = 35 \text{ mA}$, $R_{bias} = (V_s - V_{cc}) / I_{cc}$

Supply Voltage (Vs)	5V	8V	10V	12V
RBIAS VALUE	56 Ω	130 Ω	180 Ω	240 Ω
RBIAS POWER RATING	1/8 W	1/4 W	1/4 W	1/2 W

Note:

- External blocking capacitors are required on RFIN and RFOUT.
- RBIAS provides DC bias stability over temperature.

Recommended Component Values for Key Application Frequencies

Component	Frequency (MHz)							
	50	900	1900	2200	2400	3500	5200	5800
L1	270 nH	56 nH	18 nH	18 nH	15 nH	8.2 nH	6.8 nH	3.3 nH
C1, C2	0.01 μF	100 pF	100 pF	100 pF	100 pF	100 pF	100 pF	100 pF

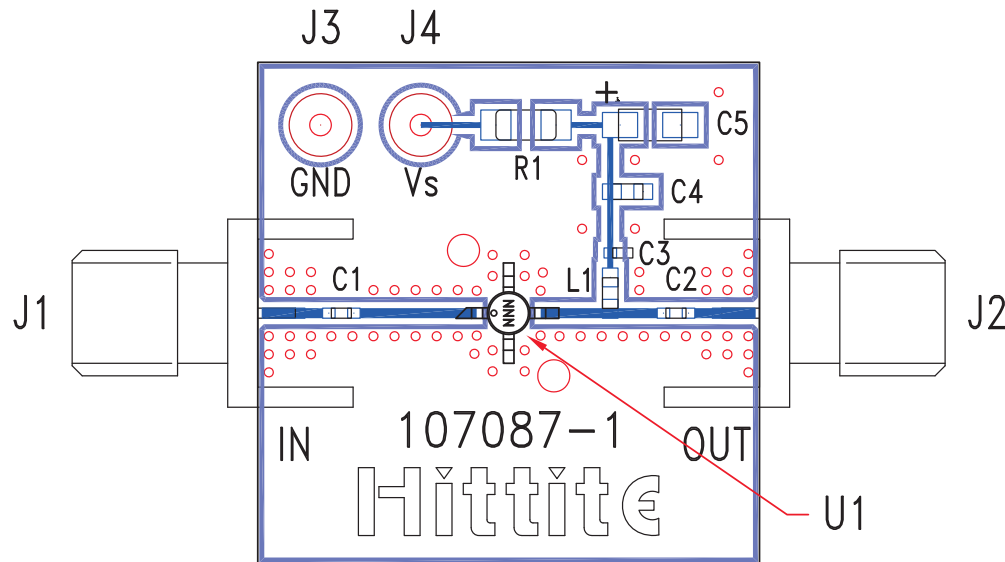
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D



**SiGe HBT GAIN BLOCK
MMIC AMPLIFIER, DC - 6 GHz**

Evaluation PCB



List of Materials for Evaluation PCB 107487 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J4	DC Pin
C1, C2	Capacitor, 0402 Pkg.
C3	100 pF Capacitor, 0402 Pkg.
C4	1000 pF Capacitor, 0603 Pkg.
C5	2.2 μ F Capacitor, Tantalum
R1	Resistor, 1210 Pkg.
L1	Inductor, 0603 Pkg.
U1	HMC476MP86 / HMC476MP86E
PCB [2]	107087 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.